NSN 5962-01-352-7919

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View Online at https://aerobasegroup.com/nsn/5962-01-352-7919

Overall Length:
0.640 inches
Overall Height:
Between 0.045 inches and 0.090 inches
Overall Width:
Between 0.800 inches and 1.160 inches
Body Length:
0.640 inches
Body Width:
Between 0.300 inches and 0.420 inches
Body Height:
Between 0.045 inches and 0.090 inches
Maximum Power Dissipation Rating:
1.04 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and schottky and monolithic and 3-state output and w/enable and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
F-6 mil-m-38510
Current Rating Per Characteristic:
190.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

15.00 input picofarads and 12.00 output picofarads

Time Rating Per Chacteristic:

40.00 nanoseconds af output megawatts

Memory Device Type:

Prom

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Fiig: A458a0



Special Features:
Nuclear hardness critical items
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.
Terminal Type And Quantity:
24 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli